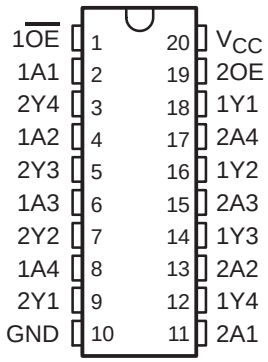
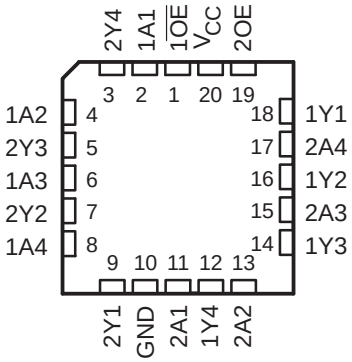
- **Inputs Are TTL Compatible**
- ***EPIC***™ **(Enhanced-Performance Implanted CMOS) 1-μm Process**
- **Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and DIP (N) Packages, Ceramic Chip Carriers (FK), Flat (W), and DIP (J) Packages**

SN54ACT241 . . . J OR W PACKAGE
SN74ACT241 . . . DB, DW, N, OR PW PACKAGE
(TOP VIEW)



SN54ACT241 . . . FK PACKAGE
(TOP VIEW)



description

These octal buffers and line drivers are designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The ’ACT241 are organized as two 4-bit buffers/drivers with separate complementary output-enable ($1\overline{OE}$ and 2OE) inputs. When $1\overline{OE}$ is low or 2OE is high, the device passes noninverted data from the A inputs to the Y outputs. When $1\overline{OE}$ is high or 2OE is low, the outputs are in the high-impedance state.

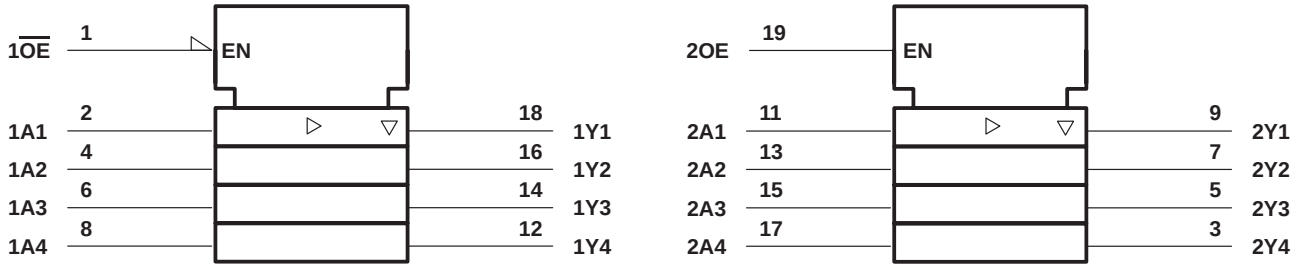
The SN54ACT241 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ACT241 is characterized for operation from –40°C to 85°C.

FUNCTION TABLES

INPUTS		OUTPUT
$1\overline{OE}$	1A	1Y
L	H	H
L	L	L
H	X	Z

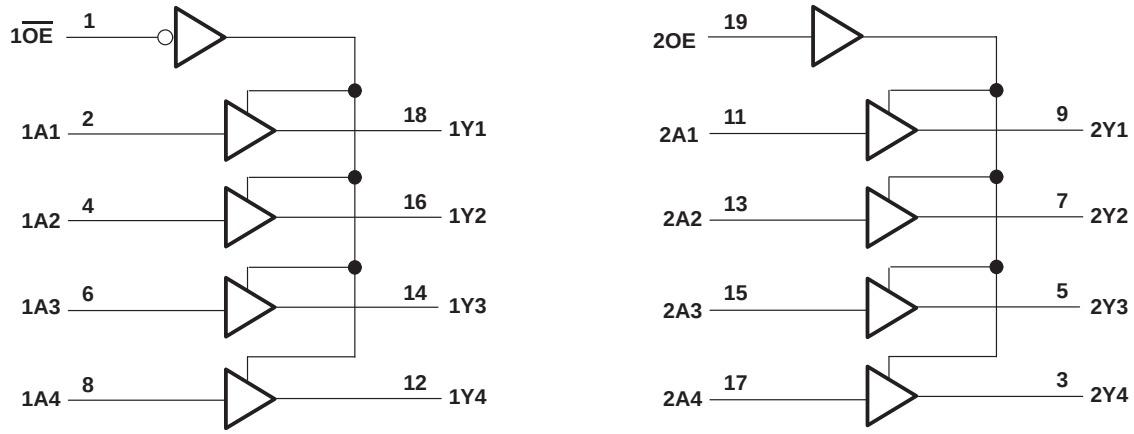
INPUTS		OUTPUT
2OE	2A	2Y
H	H	H
H	L	L
L	X	Z

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V_{CC} . . . . . –0.5 V to 7 V
Input voltage range, V_I (see Note 1) . . . . . –0.5 V to V_{CC} + 0.5 V
Output voltage range, V_O (see Note 1) . . . . . –0.5 V to V_{CC} + 0.5 V
Input clamp current, I_{IK} (V_I < 0 or V_I > V_{CC}) . . . . . ±20 mA
Output clamp current, I_{OK} (V_O < 0 or V_O > V_{CC}) . . . . . ±20 mA
Continuous output current, I_O (V_O = 0 to V_{CC}) . . . . . ±50 mA
Continuous current through V_{CC} or GND . . . . . ±200 mA
Maximum power dissipation at T_A = 55°C (in still air) (see Note 2): DB package . . . . . 0.6 W
D package . . . . . 1.6 W
N package . . . . . 1.3 W
PW package . . . . . 0.7 W
Storage temperature range, T_{stg} . . . . . –65°C to 150°C

‡ Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the N package, which has a trace length of zero.

recommended operating conditions (see Note 3)

		SN54ACT241		SN74ACT241		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
V_I	Input voltage	0	V_{CC}	0	V_{CC}	V
V_O	Output voltage	0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current		–24		–24	mA
I_{OL}	Low-level output current		24		24	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	8	0	8	ns/V
T_A	Operating free-air temperature	–55	125	–40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V_{CC}	T_A = 25°C			SN54ACT241		SN74ACT241		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V_{OH}	I_{OH} = –50 µA	4.5 V	4.4	4.49		4.4		4.4		V
		5.5 V	5.4	5.49		5.4		5.4		
	I_{OL} = –24 mA	4.5 V	3.86			3.7		3.76		
		5.5 V	4.86			4.7		4.76		
	I_{OH} = –50 mA†	5.5 V				3.85				
	I_{OH} = –75 mA†	5.5 V						3.85		
V_{OL}	I_{OL} = 50 µA	4.5 V		0.001	0.1		0.1		0.1	V
		5.5 V		0.001	0.1		0.1		0.1	
	I_{OL} = 24 mA	4.5 V			0.36		0.5		0.44	
		5.5 V			0.36		0.5		0.44	
	I_{OL} = 50 mA†	5.5 V					1.65			
	I_{OL} = 75 mA†	5.5 V							1.65	
I_{OZ}	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±5		±2.5	µA
I_I	$V_I = V_{CC}$ or GND	5.5 V			±0.1		±1		±1	µA
I_{CC}	$V_I = V_{CC}$ or GND, I_O = 0	5.5 V			4		80		40	µA
ΔI_{CC}‡	One input at 3.4 V, Other inputs at GND or V_{CC}	5.5 V		0.6			1.6		1.5	mA
C_i	$V_I = V_{CC}$ or GND	5 V		2.5						pF
C_o	$V_I = V_{CC}$ or GND	5 V		8						pF

† Not more than one output should be tested at a time, and the duration of the test should not exceed 2 ms.
‡ This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

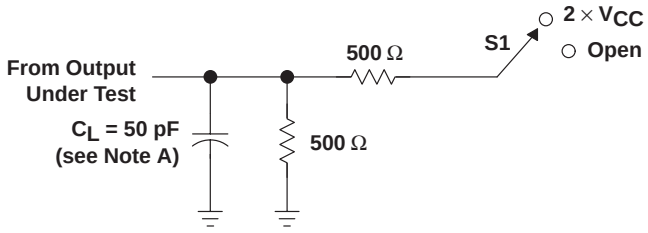
switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	T_A = 25°C			SN54ACT241		SN74ACT241		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	Y	1.5	6	8.5	1	9.5	1.5	9.5	ns
t_{PHL}			1.5	5.5	7.5	1	9	1.5	8.5	
t_{PZH}	$\overline{OE}$ or OE	Y	1.5	7	8.5	1	10	1	9.5	ns
t_{PZL}			2	7	9.5	1	11.5	1.5	10.5	
t_{PHZ}	$\overline{OE}$ or OE	Y	2	8	9.5	1	11	2	10.5	ns
t_{PLZ}			2.5	6.5	10	1	11.5	2	10.5	

operating characteristics, V_{CC} = 5 V, T_A = 25°C

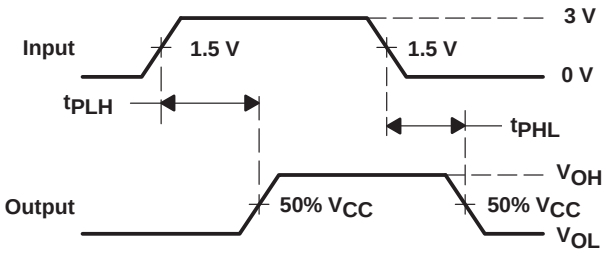
PARAMETER		TEST CONDITIONS		TYP	UNIT
C_{pd}	Power dissipation capacitance per buffer/driver	C_L = 50 pF,	f = 1 MHz	45	pF

PARAMETER MEASUREMENT INFORMATION

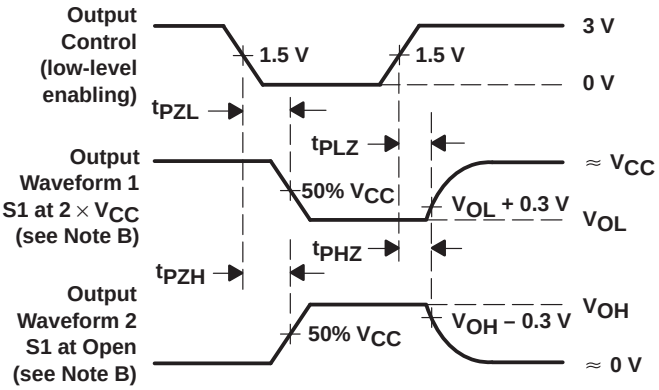


TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	2 × V_{CC}
t_{PHZ}/t_{PZH}	Open

LOAD CIRCUIT



VOLTAGE WAVEFORMS



VOLTAGE WAVEFORMS

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.
D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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SN74ACT241, Octal Buffers / Drivers With 3-State Outputs

DEVICE STATUS: **ACTIVE**

PARAMETER NAME	SN54ACT241	SN74ACT241
Voltage Nodes (V)	5	5
Vcc range (V)	4.5 to 5.5	4.5 to 5.5
Input Level	TTL	TTL
Output Level	CMOS	CMOS
Output Drive (mA)		-24/24
tpd max (ns)		9.5
Static Current		0.04

FEATURES

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- Inputs Are TTL Compatible
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DESCRIPTION

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TECHNICAL DOCUMENTS

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To view the following documents, Acrobat Reader 4.0 is required.
To download a document to your hard drive, right-click on the link and choose 'Save'.

DATASHEET

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Full datasheet in Acrobat PDF: sn74act241.pdf (83 KB,Rev.B) (Updated: 05/01/1996)

APPLICATION NOTES

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View Application Notes for Digital Logic

- CMOS Power Consumption and CPD Calculation (Rev. B) (SCAA035B - Updated: 06/01/1997)
- Designing With Logic (Rev. C) (SDYA009C - Updated: 06/01/1997)
- Evaluation of Nickel/Palladium/Gold-Finished Surface-Mount Integrated Circuits (SZZA026 - Updated: 06/20/2001)
- Implications of Slow or Floating CMOS Inputs (Rev. C) (SCBA004C - Updated: 02/01/1998)
- Timing Differences of 10-pF Versus 50pF Loading (SCEA004 - Updated: 11/01/1996)
- Using High Speed CMOS and Advanced CMOS in Systems With Multiple Vcc (SCLA008 - Updated: 04/01/1996)

RELATED DOCUMENTS

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View Related Documentation for Digital Logic

- Logic Reference Guide (SCYB004, 1032 KB - Updated: 10/23/2001)
- Logic Selection Guide Second Half 2002 (Rev. R) (SDYU001R, 4274 KB - Updated: 07/19/2002)
- Military Semiconductors Selection Guide 2002 (Rev. B) (SGYC003B, 1648 KB - Updated: 04/22/2002)

SAMPLES

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ORDERABLE DEVICE	PACKAGE INDUSTRY (TI)	PINS	TEMP (°C)	STATUS	PRODUCT CONTENT	SAMPLES
SN74ACT241DBR	SSOP (DB)	20	-40 TO 85	ACTIVE	View Product Content	Request Samples
SN74ACT241DW	SOP (DW)	20	-40 TO 85	ACTIVE	View Product Content	Request Samples
SN74ACT241N	PDIP (N)	20	-40 TO 85	ACTIVE	View Product Content	Request Samples
SN74ACT241PWR	TSSOP (PW)	20	-40 TO 85	ACTIVE	View Product Content	Request Samples

PRICING/AVAILABILITY/PKG

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DEVICE INFORMATION							TI INVENTORY STATUS AS OF 3:00 PM GMT, 26 Sep 2002			REPORTED DISTRIBUTOR INVENTORY AS OF 3:00 PM GMT, 26 Sep 2002		
ORDERABLE DEVICE	STATUS	PACKAGE TYPE|PINS	TEMP (°C)	PRODUCT CONTENT	BUDGETARY PRICING QTY | $US	STD PACK QTY	IN STOCK	IN PROGRESS QTY|DATE	LEAD TIME	DISTRIBUTOR COMPANY|REGION	IN STOCK	PURCHASE
SN74ACT241DBLE	OBSOLETE	SSOP (DB) | 20	-40 TO 85	View Contents	1KU |		N/A*		Not Available			
SN74ACT241DBR	ACTIVE	SSOP (DB) | 20	-40 TO 85	View Contents	1KU | 0.32	2000	2000	1320 | 25 Sep	8 WKS			
								>10k | 21 Oct				
SN74ACT241DW	ACTIVE	SOP (DW) | 20	-40 TO 85	View Contents	1KU | 0.32	25	675	>10k | 21 Oct	8 WKS			
SN74ACT241DWR	ACTIVE	SOP (DW) | 20	-40 TO 85	View Contents	1KU | 0.32	2000	N/A*	>10k | 18 Oct	8 WKS			
SN74ACT241N	ACTIVE	PDIP (N) | 20	-40 TO 85	View Contents	1KU | 0.32	20	N/A*	5 | 23 Sep	8 WKS	Avnet | AMERICA	220	BUY NOW

								>10k | 21 Oct						
SN74ACT241NSR	ACTIVE	SOP (NS) | 20		View Contents	1KU | 0.45	2000	N/A*	>10k | 21 Oct	8 WKS					
SN74ACT241PWLE	OBSOLETE	TSSOP (PW) | 20	-40 TO 85	View Contents	1KU |		N/A*		Not Available					
SN74ACT241PWR	ACTIVE	TSSOP (PW) | 20	-40 TO 85	View Contents	1KU | 0.32	2000	2000	1039 | 25 Sep	8 WKS					
								>10k | 17 Oct						
								>10k | 24 Oct						

Table Data Updated on: 9/26/2002